

substance: YbS

property: crystal structure, physical properties

crystal structure cubic ($O_h^5 - Fm3m$)

lattice parameters

a	5.692 Å	71B
	5.691 Å	78M

energy gap

E_g	≈0.4 eV	4f-cond. band	X-ray spectroscopy	82G
	3.2 eV	val.-cond. band	(K, L _{2,3} -emission, K-absorption)	
	0.98 eV		optical spectroscopy	71B
	1.1 eV			74N
	1.325(5) eV	4f → conduction band transition		80G
dE_g/dp	− 6.5 meV kbar ^{−1}			74N

bulk modulus

B_0	720(50) kbar	74J
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phonon wavenumbers

$(\nu/c)_{TO}$	199(3) cm ^{−1}		IR measurements	78M
	203 (3) cm ^{−1}	$T = 77$ K		
$(\nu/c)_{LO}$	272(3) cm ^{−1}			
	276(3) cm ^{−1}	$T = 77$ K		

dielectric constants

$\epsilon(0)$	9.5(5)		78M
	9.6(5)	$T = 77$ K	
$\epsilon(\infty)$	5.0(5)		
	5.0 (5)	$T = 77$ K	

energy gap

E	1.8 eV	4f ¹⁴ (1S ₀) → 4f ¹³ (² F _{7/2})5d transition;	80G
	2.8 eV	4f ¹⁴ (1S ₀) → 4f ¹³ (² F _{5/2})5d transition	

activation energy for conductivity

E_A	0.3...0.4 eV	p-type	80G
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Figures and further references:

optical absorption: Figs. 1, 2, pressure dependence of the absorption spectrum: Fig. 3

photocurrent and photo-emf: Fig. 4

Raman spectrum: Fig. 5

traps due to non-stoichiometry; bulk and surface states [82M]

References:

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Fig. 1.

Yb-chalcogenides. Absorption coefficient vs. wavelength (photon energy) for thin films on NaCl substrates at atmospheric pressure [74N].

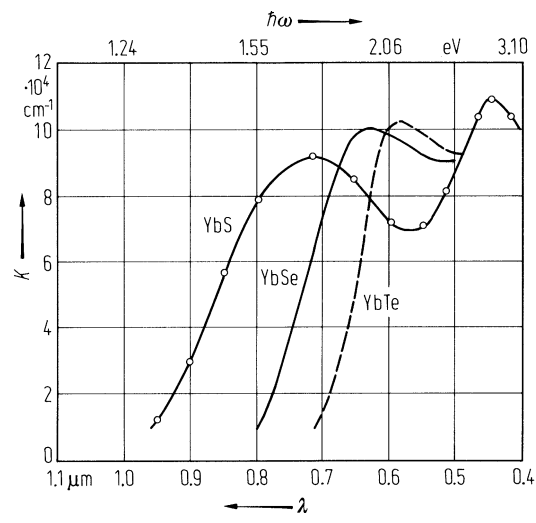


Fig. 2.

YbS. Absorption coefficient (1) and absorption coefficient times photon energy (2) vs. photon energy for a 0.3 μm thick film [80G].

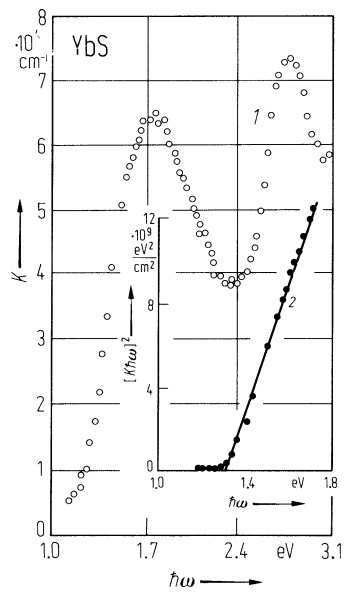


Fig. 3.

YbS. Absorption edge at atmospheric pressure and at 6 kbar vs. wavelength (photon energy) [74N].

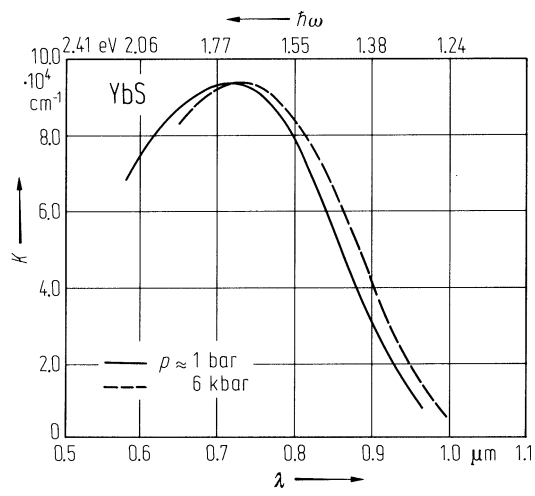


Fig. 4.

YbS. Photocurrent (*I*) and photo-emf (2) vs. photon energy of a 2.8 μm thick film [80G].

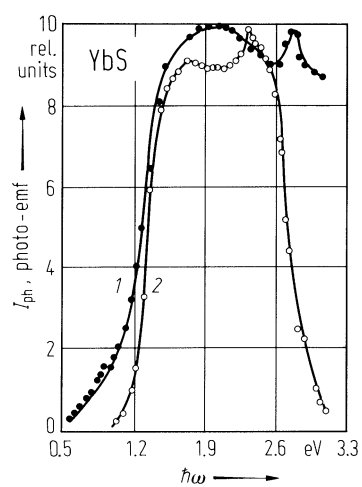


Fig. 5.

YbS. Raman spectra (intensity vs. Raman shift) for different exciting laser energies [78M].

